MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet



Features

- 100Watts peak pulse power (tp = $8/20\mu$ s)
- Tiny DFN1006 package
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance (Cj=0.25pF typ. IO to IO)
- Protection one data/power line to:
- IEC 61000-4-2 ±20kV contact ±20kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 4A (8/20μs)



PIN CONFIGURATION

DFN1006

Applications

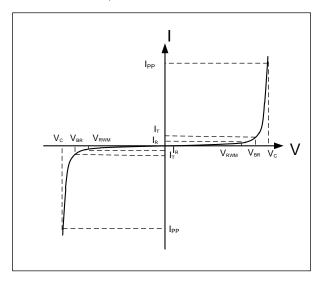
- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- **0**402
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Electrical Parameters (TA = $25 \, ^{\circ}$ C unless otherwise noted)

Symbol	Parameter	
IPP	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ Ipp	
V _{RWM}	Working Peak Reverse Voltage	
IR	Maximum Reverse Leakage Current @ VRWM	
V _{BR}	Breakdown Voltage @ IT	
Iτ	Test Current	



Note: $8/20\mu s$ pulse waveform.



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Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20μs)	P_{PP}	100	Watts
Peak Pulse Current (t _p =8/20μs) (note1)	I_{pp}	4.0	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$ m V_{ESD}$	20 20	kV
Lead Soldering Temperature	${ m T_L}$	260(10seconds)	$^{\circ}$
Junction Temperature	T_{J}	-55 to + 125	°C
Storage Temperature	T_{stg}	-55 to + 125	$^{\circ}$

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	6.0			V
Reverse Leakage Current	I_R	V _{RWM} =5V,T=25℃			100	nA
Peak Pulse Current	I_{PP}	tp =8/20μs			4.0	A
Clamping Voltage	V _C	I _{PP} =4A,t _p =8/20μs			25	V
Junction Capacitance	C _j	IO to IO $V_R = 0V, f = 1MHz$		0.25	0.4	pF



Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

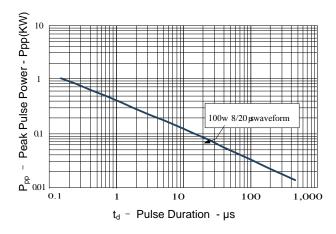


Figure3: Pulse Waveform

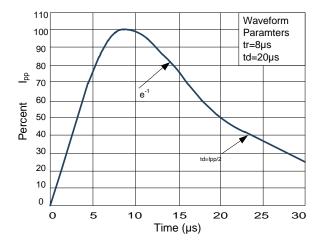


Figure 5: Positive Clamping voltage (TLP)

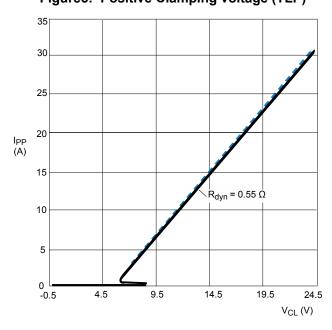


Figure 2: Power Derating Curve

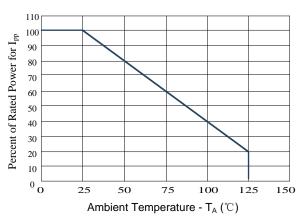


Figure 4: Clamping Voltage vs.lpp

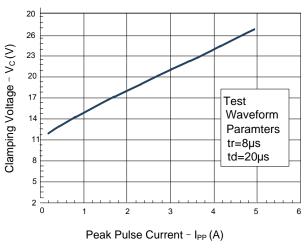
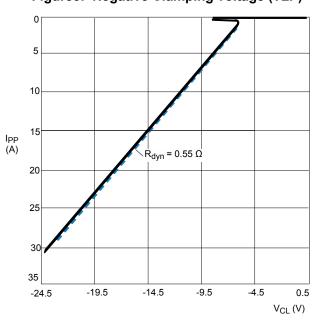
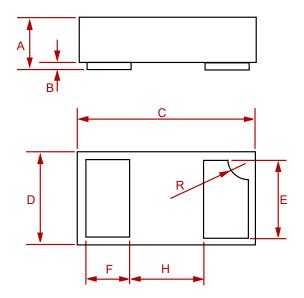


Figure 5: Negative Clamping voltage (TLP)



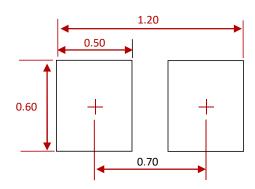


PACKAGE MECHANICAL DATA



Dim	Inches		Millimeters		
	MIN	MAX	MIN	MAX	
Α	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
Е	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40	Тур.	
R	0.001	0.005	0.05	0.15	

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
PESDUC2FD5VB-MS	DFN1006	10000



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